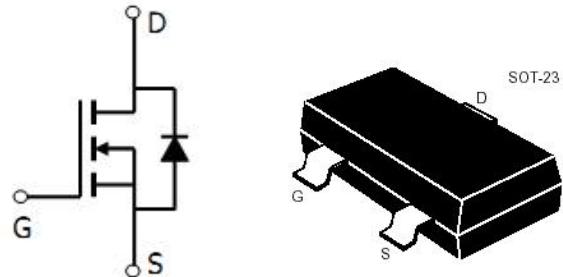


GMN6521

SOT-23 場效應晶體管(SOT-23 Field Effect Transistors)



### N-Channel Enhancement-Mode MOS FETs

N 溝道增強型 MOS 場效應管

#### ■MAXIMUM RATINGS 最大額定值

Characteristic 特性參數	Symbol 符號	Rat 額定值	Unit 單位
Drain-Source Voltage 漏極-源極電壓	$BV_{DSS}$	650	V
Gate- Source Voltage 柵極-源極電壓	$V_{GS}$	$\pm 30$	V
Drain Current (continuous) 漏極電流 - 連續	$I_D$	210	mA
Drain Current (pulsed) 漏極電流 - 脉冲	$I_{DM}$	2	A
Total Device Dissipation 總耗散功率 TA=25°C 環境溫度為 25°C	$P_D$	900	mW
Junction 結溫	$T_J$	150	°C
Storage Temperature 儲存溫度	$T_{stg}$	-55 to +150	°C

#### ■DEVICE MARKING 打標

GMN6521=M21
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**桂林斯壯桂微電子有限公司**  
**GSME Guilin Strong Micro-Electronics Co.,Ltd.**

GMN6521

**ELECTRICAL CHARACTERISTICS 電特性**

( $T_A=25^\circ\text{C}$  unless otherwise noted 如無特殊說明，溫度為  $25^\circ\text{C}$ )

Characteristic 特性參數	Symbol 符號	Min 最小值	Typ 典型值	Max 最大值	Unit 單位
Drain-Source Breakdown Voltage 漏極-源極擊穿電壓( $I_D = 250\mu\text{A}$ , $V_{GS} = 0\text{V}$ )	$\text{BV}_{DSS}$	650	—	—	V
Gate Threshold Voltage 柵極開啓電壓( $I_D = 250\mu\text{A}$ , $V_{GS} = V_{DS}$ )	$V_{GS(\text{th})}$	2.5	—	3.8	V
Diode Forward Voltage Drop 內附二極管正向壓降( $I_S = 2\text{A}$ , $V_{GS} = 0\text{V}$ )	$V_{SD}$	—	—	1.2	V
Zero Gate Voltage Drain Current 零柵壓漏極電流( $V_{GS} = 0\text{V}$ , $V_{DS} = 500\text{V}$ )	$I_{DSS}$	—	—	1	$\mu\text{A}$
Gate Body Leakage 柵極漏電流( $V_{GS} = \pm 30\text{V}$ , $V_{DS} = 0\text{V}$ )	$I_{GSS}$	—	—	$\pm 100$	nA
Static Drain-Source On-State Resistance 靜態漏源導通電阻( $I_D = 0.5\text{A}$ , $V_{GS} = 10\text{V}$ )	$R_{DS(\text{ON})}$	—	16	19	$\Omega$
Input Capacitance 輸入電容 ( $V_{GS} = 0\text{V}$ , $V_{DS} = 400\text{V}$ , $f = 1\text{MHz}$ )	$C_{ISS}$	—	120	—	pF
Output Capacitance 輸出電容 ( $V_{GS} = 0\text{V}$ , $V_{DS} = 400\text{V}$ , $f = 1\text{MHz}$ )	$C_{OSS}$	—	20	—	pF
Turn-ON Time 开啓時間 ( $V_{DS} = 300\text{V}$ , $I_D = 0.2\text{A}$ , $R_{GEN} = 6\Omega$ )	$t_{(\text{on})}$	—	6	—	ns
Turn-OFF Time 短斷時間 ( $V_{DS} = 300\text{V}$ , $I_D = 0.2\text{A}$ , $R_{GEN} = 6\Omega$ )	$t_{(\text{off})}$	—	8	—	ns

Pulse Width  $\leq 300\ \mu\text{s}$ ; Duty Cycle  $\leq 2.0\%$